## High Power <br> Diode Modules

| $V_{\text {RSM }}$ <br> $V$ | $V_{\text {RRM }}$ <br> $V$ | Type |
| :---: | :---: | :--- |
| 1300 | 1200 | MDD 250-12N1 |
| 1500 | 1400 | MDD 250-14N1 |
| 1700 | 1600 | MDD 250-16N1 |



| Symbol | Conditions |  |  | Maximum Ratings |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\overline{I_{\text {FRMS }}}$ $\mathrm{I}_{\mathrm{FAVM}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{VJ}}=\mathrm{T}_{\mathrm{vJM}} \\ & \mathrm{~T}_{\mathrm{C}}=100^{\circ} \mathrm{C} ; 180^{\circ} \text { sine } \end{aligned}$ |  |  | 450 290 | A |
| $\mathrm{I}_{\text {FSM }}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{V} J}=45^{\circ} \mathrm{C} ; \\ & \mathrm{V}_{\mathrm{R}}=0 \end{aligned}$ | $\begin{aligned} & \mathrm{t}=10 \mathrm{~ms} \\ & \mathrm{t}=8.3 \mathrm{~ms} \end{aligned}$ | $\begin{aligned} & \hline(50 \mathrm{~Hz}) \\ & (60 \mathrm{~Hz}) \end{aligned}$ | $\begin{array}{r} 11 \\ 11,7 \end{array}$ | kA |
|  | $\begin{aligned} & \mathrm{T}_{\mathrm{VJ}}=\mathrm{T}_{\mathrm{VJM}} ; \\ & \mathrm{V}_{\mathrm{R}}=0 \end{aligned}$ | $\begin{aligned} & \mathrm{t}=10 \mathrm{~ms} \\ & \mathrm{t}=8.3 \mathrm{~ms} \end{aligned}$ | $\begin{aligned} & (50 \mathrm{~Hz}) \\ & (60 \mathrm{~Hz}) \end{aligned}$ | 9 9,6 | kA kA |
| ${ }^{12} \mathrm{t}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{Vv}}=45^{\circ} \mathrm{C} ; \\ & \mathrm{V}_{\mathrm{R}}=0 \end{aligned}$ | $\begin{aligned} & \mathrm{t}=10 \mathrm{~ms} \\ & \mathrm{t}=8.3 \mathrm{~ms} \end{aligned}$ | $\begin{aligned} & (50 \mathrm{~Hz}) \\ & (60 \mathrm{~Hz}) \\ & \hline \end{aligned}$ | $\begin{aligned} & 605 \\ & 560 \\ & \hline \end{aligned}$ | $\begin{aligned} & {k A^{2} \mathrm{~S}}^{\mathrm{kA}} \mathrm{~S} \end{aligned}$ |
|  | $\begin{aligned} & \mathrm{T}_{\mathrm{vJ}}=\mathrm{T}_{\mathrm{vJM}} ; \\ & \mathrm{V}_{\mathrm{R}}=0 \end{aligned}$ | $\begin{aligned} & \mathrm{t}=10 \mathrm{~ms} \\ & \mathrm{t}=8.3 \mathrm{~ms} \end{aligned}$ | $\begin{aligned} & (50 \mathrm{~Hz}) \\ & (60 \mathrm{~Hz}) \end{aligned}$ | $\begin{aligned} & 405 \\ & 380 \end{aligned}$ | $\begin{aligned} & {k A^{2} s}^{k A^{2} s} . \end{aligned}$ |
| $\begin{aligned} & \hline \mathbf{T}_{\mathrm{vJ}} \\ & \mathbf{T}_{\mathrm{vJM}} \\ & \mathbf{T}_{\text {stg }} \end{aligned}$ |  |  |  | $\begin{array}{r} -40 \ldots+150 \\ 150 \\ -40 \ldots+125 \end{array}$ | ${ }^{\circ} \mathrm{C}$ <br> ${ }^{\circ} \mathrm{C}$ <br> ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{V}_{\text {ISOL }}$ | 50/60 Hz, RMS $\mathrm{I}_{\mathrm{ISOL}} \leq 1 \mathrm{~mA}$ | $\begin{aligned} & t=1 \mathrm{~min} \\ & t=1 \mathrm{~s} \end{aligned}$ |  | $\begin{aligned} & 3000 \\ & 3600 \end{aligned}$ | V V |
| $\mathbf{M}_{\text {d }}$ | Mounting torque (M5) |  |  | $\begin{array}{r} 2.5-5 \\ 12-15 \end{array}$ | Nm Nm |
| Weight | Typical including screws |  |  | 320 | g |


| Symbol | Conditions | Characteristics V | lues |
| :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\text {RRM }}$ | $\mathrm{V}_{\mathrm{R}}=\mathrm{V}_{\text {RRM }} ; \quad \mathrm{T}_{\mathrm{VJ}}=\mathrm{T}_{\mathrm{VJM}}$ | 40 | mA |
| $\mathrm{V}_{\mathrm{F}}$ | $\mathrm{I}_{\mathrm{F}}=600 \mathrm{~A} ; \quad \mathrm{T}_{\mathrm{VJ}}=25^{\circ} \mathrm{C}$ | 1.3 | V |
| $\mathrm{V}_{\text {T0 }}$ | For power-loss calculations only | 0.75 | V |
| $\mathrm{r}_{\text {t }}$ | $\mathrm{T}_{\mathrm{V},}=\mathrm{T}_{\mathrm{V} \text { M }}$ | 0.75 | $\mathrm{m} \Omega$ |
| $\mathrm{R}_{\text {thJc }}$ | per diode; DC current | 0.129 | K/W |
|  | per module other values | 0.065 | K/W |
| $\mathbf{R}_{\text {thJK }}$ | per diode; DC current per module | 0.169 | K/W |
|  |  | 0.0845 | K/W |
| $\mathbf{Q}_{\text {s }}$ | $\mathrm{T}_{\mathrm{V} J}=125^{\circ} \mathrm{C} ; \mathrm{I}_{\mathrm{F}}=400 \mathrm{~A} ;-\mathrm{di} / \mathrm{dt}=50 \mathrm{~A} / \mu \mathrm{s}$ | 760 | $\mu \mathrm{C}$ |
| $\mathrm{I}_{\text {RM }}$ |  | 275 | A |
| $\mathrm{d}_{\text {s }}$ | Creeping distance on surface | 12.7 | mm |
| $\mathrm{d}_{\mathrm{A}}$ | Creepage distance in air | 9.6 | mm |
| a | Maximum allowable acceleration | 50 | $\mathrm{m} / \mathrm{s}^{2}$ |

[^0]$I_{\text {FRSM }}=2 \times 450 \mathrm{~A}$
$I_{\text {FAVM }}=2 \times 290 \mathrm{~A}$
$V_{\text {RRM }}=1200-1600 \mathrm{~V}$


## Features

- Direct copper bonded $\mathrm{Al}_{2} \mathrm{O}_{3}$ ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873


## Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies


## Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits


## GIXYS

Dimensions in mm (1 mm = 0.0394")


Threaded spacer for higher Anode / Cathode construction:

Type ZY 250 (material brass)



Fig. 1 Surge overload current ${ }_{\text {FSMM }}$ : Crest value, t: duration


Fig. $21^{2}$ dt versus time ( $1-10 \mathrm{~ms}$ )


Fig. 2a Maximum forward current at case temperature

Fig. 3 Power dissipation vs. forward current and ambient temperature (per diode)

$R=$ resistive load
L = inductive load

Fig. 4 Single phase rectifier bridge: Power dissipation vs. direct output current and ambient
IXYS reserves the right to change limits, test conditions and dimensions.


Fig. 5 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature


Fig. 7 Transient thermal impedance junction to case (per diode)


Fig. 8 Transient thermal impedance junction to heatsink (per diode)
$R_{\text {thJk }}$ for various conduction angles $d$ :

| $\mathbf{d}$ | $R_{\text {thJK }}(K / W)$ |
| :---: | :---: |
| $D C$ | 0.169 |
| $180^{\circ}$ | 0.171 |
| $120^{\circ}$ | 0.172 |
| $60^{\circ}$ | 0.172 |
| $30^{\circ}$ | 0.173 |

Constants for $Z_{\text {thJK }}$ calculation:

| $\mathbf{i}$ | $\mathbf{R}_{\text {thi }}(\mathrm{K} / \mathrm{W})$ | $\mathbf{t}_{\mathbf{i}}(\mathbf{s})$ |
| :--- | :--- | :--- |
| 1 | 0.0035 | 0.0099 |
| 2 | 0.0165 | 0.168 |
| 3 | 0.1091 | 0.456 |
| 4 | 0.04 | 1.36 |

## X-ON Electronics

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| M252511FV | DD260N12K-A | DD380N16A | DD89N1600K | APT2X21D | C60J APT58M | 80J B522F-2-Y | EEC MSTC90-16 | 1625.163 | 3.0653 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 25.163.2453.0 | 25.163.4253.0 | 25.190.2053.0 | 25.194.3453.0 | 25.320.4853.1 | 25.320.5253.1 | 25.326.3253.1 | 25.326.3553.1 | 25.330.1 | 1653.1 |
| 25.330.4753.1 | 25.330.5253.1 | 25.334.3253.1 | 25.334.3353.1 | 25.350.2053.0 | 25.352.4753.1 | 25.522.3253.0 | T483C T484C | T485F | T485 |
| T512F-YEB | T513F T514F | T554 T612FSE | 25.161.3453.0 | 25.179.2253.0 | 25.194.3253.0 | 25.325.1253.1 | 25.326.4253.1 | 25.330.0 | 0953.1 |
| 25.332.4353.1 | 25.350.1653.0 | 25.350.2453.0 | 25.352.1453.0 | 25.352.1653.0 | 25.352.2453.0 | 25.352.5453.1 | 25.522.3353.0 | 25.602.4 | 4053.0 |
| 25.640.5053.0 |  |  |  |  |  |  |  |  |  |


[^0]:    Data according to IEC 60747 and refer to a single diode unless otherwise stated.

